FAIRCHILD

SEMICONDUCTOR®

FDP5500_F085

N-Channel UltraFET Power MOSFET

55V, 80A, 7m Ω

Features

- Typ $r_{DS(on)}$ = 5.1m Ω at V_{GS} = 10V, I_D = 80A
- Typ Q_{g(10)} = 114nC at V_{GS} = 10V
- Simulation Models
 -Temperature Compensated PSPICE and SABERTM Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Qualified to AEC Q101
- RoHS Compliant

Applications

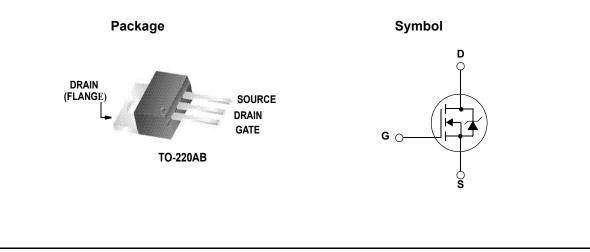
- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems



April 2009

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Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage	(Note 1)	55	V
V _{DGR}	Drain to Gate Voltage (R_{GS} = 20k Ω)	(Note 1)	55	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 135 ^o C, V _{GS} = 10V)		80	Α
D	Pulsed		See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	860	mJ
П	Power Dissipation		375	W
P _D	Derate above 25°C		2.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	
ΤL	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T _{pkg}	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.4	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-220AB, 1in ² copper pad area	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP5500	FDP5500_F085	TO-220AB	Tube	N/A	50 units

Electrical Characteristics T_{C} = 25°C unless otherwise noted

Sy	mbol	Parameter	Test Conditions	Min	Тур	Max	Units

Off Characteristics

B_{VDSS}	Drain to Source Breakdown Voltage	$I_{\rm D}$ = 250 μ A, V _{GS} = 0'	V	55	-	-	V
	Zero Gate Voltage Drain Current	V _{DS} = 50V, V _{GS} = 0	IV .	-	-	1	
DSS	Zero Gale voltage Drain Current	V _{DS} = 45V	T _C = 150 ^o C	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.8	4	V
r _{DS(on)}	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V	-	5.1	7	mΩ

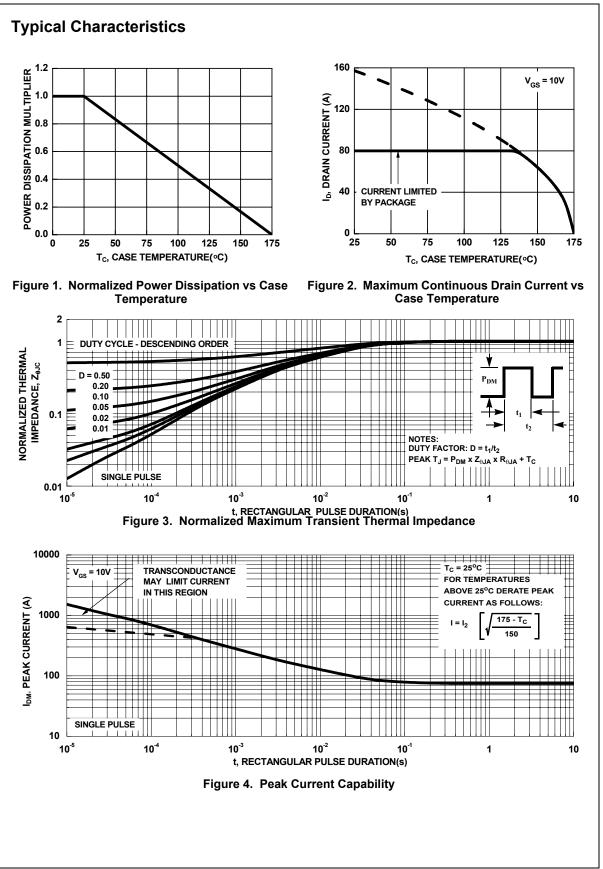
Dynamic Characteristics

C _{iss}	Input Capacitance		0)/	-	3565	-	pF
C _{oss}	Output Capacitance	───V _{DS} = 25V, V _{GS} = f = 1MHz	0ν,	-	1310	-	pF
C _{rss}	Reverse Transfer Capacitance			-	395	-	pF
Q _{g(TOT)}	Total Gate Charge at 20V	V _{GS} = 0 to 20V		-	207	269	nC
Q _{g(10)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	$V_{DD} = 30V$	-	114	148	nC
Q _{g(TH)}	Threshold Gate Charge	V_{GS} = 0 to 2V	I _D = 80A R ₁ = 0.4Ω	-	6.6	8.6	nC
Q _{gs}	Gate to Source Gate Charge		$I_{a} = 1.0 \text{mA}$	-	17.2	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		g	-	52	-	nC

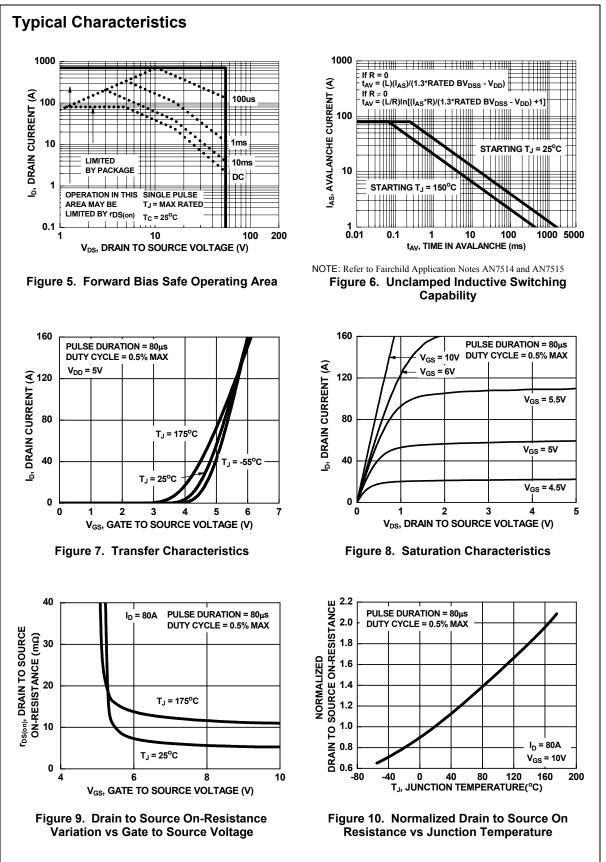
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ning Characteristics					
t _{on}	Turn-On Time		-	-	75	ns
t _{d(on)}	Turn-On Delay Time	$V_{DD} = 30V, I_D = 80A,$ 	-	12	-	ns
t _r	Rise Time		-	34	-	ns
t _{d(off)}	Turn-Off Delay Time		-	37	-	ns
t _f	Fall Time		-	23	-	ns
t _{off} Drain-S	Turn-Off Time ource Diode Characteristics		-	-	96	ns
		I _{SD} = 80A	-	- 0.9	96	ns V
Drain-S	ource Diode Characteristics					

FDP5500_F085 Rev. A

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

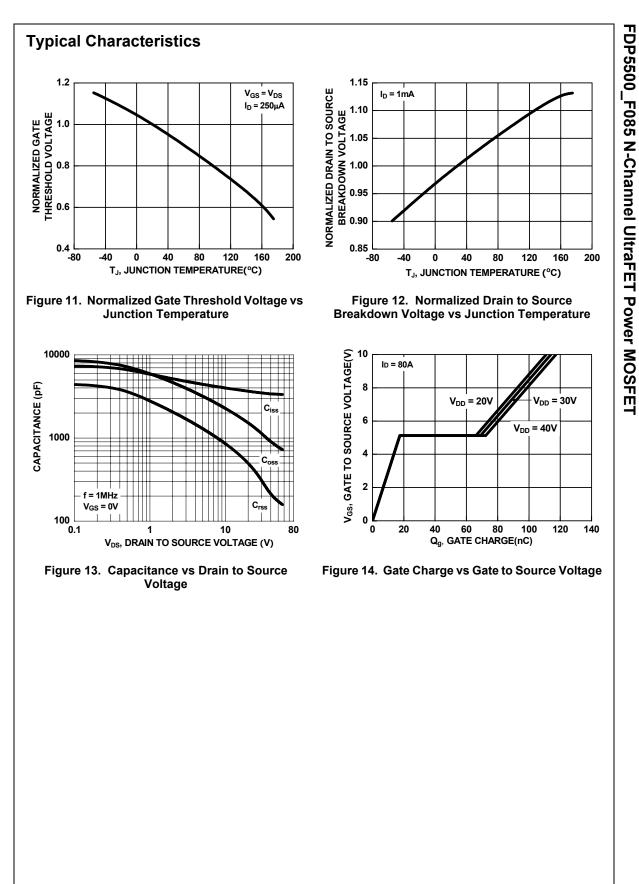


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FDP5500_F085 Rev. A





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	Formative / In Design First Production Full Production